

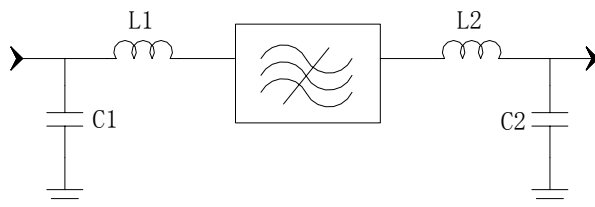
Specifications

Parameter	Unit	Minimum	Typical	Maximum
Center Frequency	MHz	159.85	160	160.15
Insertion Loss	dB	-	34	35.5
3 dB Bandwidth	MHz	16.4	16.42	-
30 dB Bandwidth	MHz	-	17.1	17.2
40 dB Bandwidth	MHz	-	17.25	17.6
50 dB Bandwidth	MHz	-	17.33	18
Passband Variation	dB	-	0.6	1
Ultimate Rejection	dB	50	52	-
Absolute Delay	usec	-	3.8	4
Material Temperature coefficient	KHz/°C	-2.88		
Ambient Temperature	°C	25		
Package Size	DIP3512 (35.2x12.7x5.2mm ³)			

Notes:


1. All specifications are based on the test circuit shown
2. In production, devices will be tested at room temperature to a guardbanded specification to ensure electrical compliance over temperature
3. Electrical margin has been built into the design to account for the variations due to temperature drift and manufacturing tolerances
4. This is the optimum impedance in order to achieve the performance show

Matching Configuration

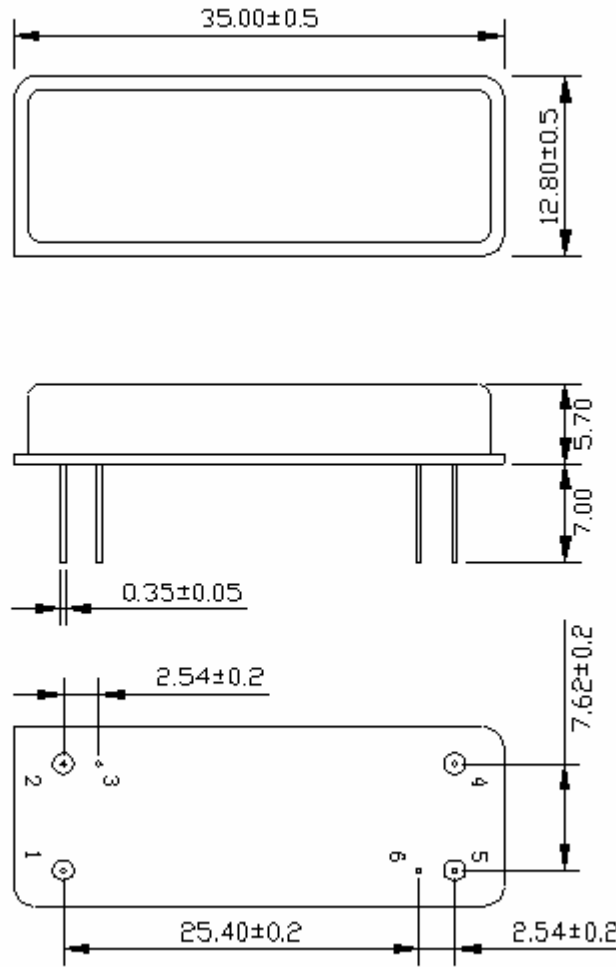


L1=18nH L2=33nH
C1=56pF C2=56pF
Source/Load Impedance=50 ohm


Notes - Component values may change depending on board layout.

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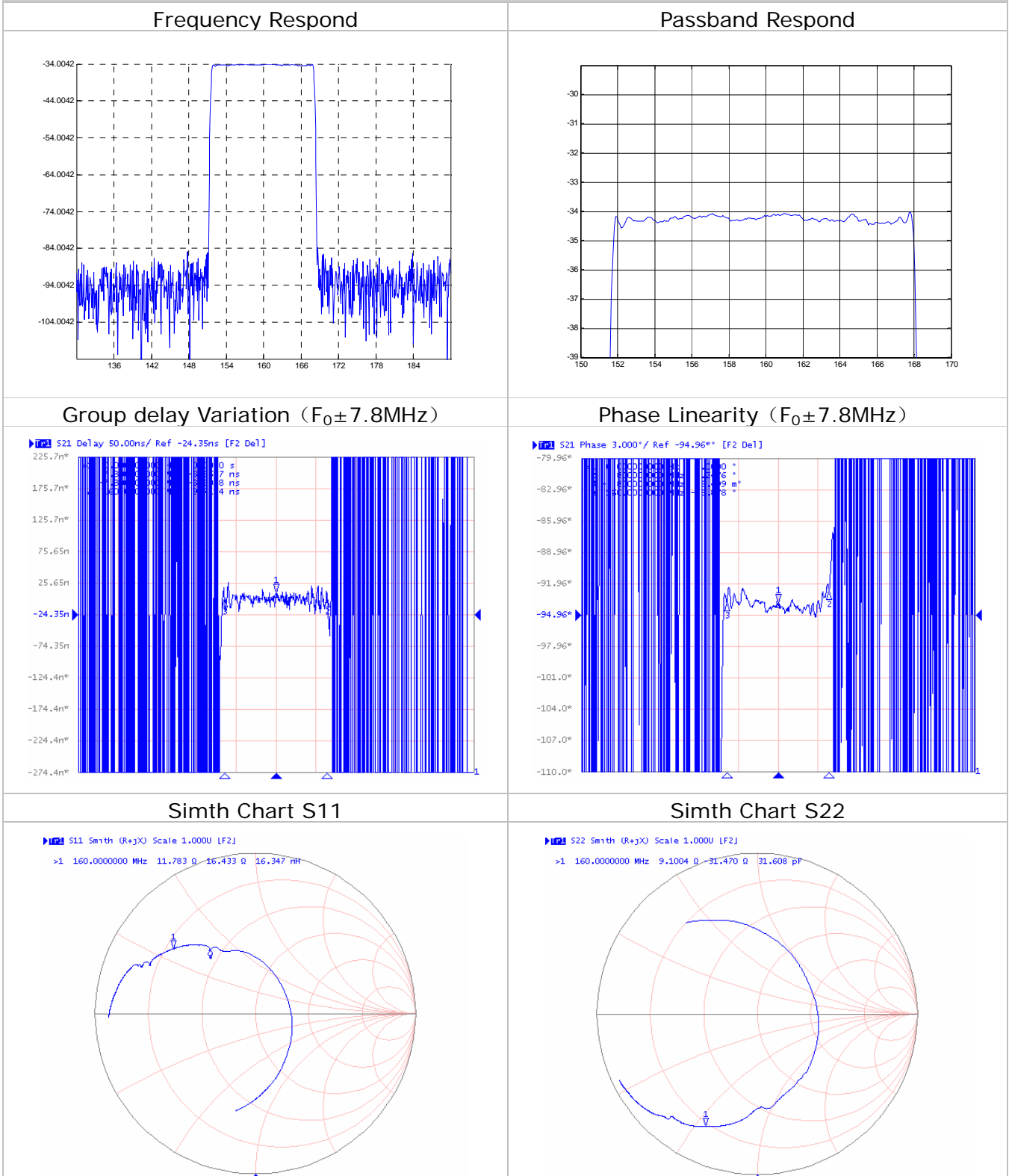
Package Dimension




Input:1
Output:5

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Typical Performance



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